

Attorney Docket No. 5308-279

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Sei-Hyung Ryu

Serial No.: 10/698,170

Filed: October 30, 2003

For: VERTICAL JFET LIMITED SILICON CARBIDE POWER METAL-OXIDE  
SEMICONDUCTOR FIELD EFFECT TRANSISTORS AND METHODS OF  
FABRICATING VERTICAL JFET LIMITED SILICON CARBIDE METAL-  
OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS

Date: November 24, 2003

Licensing and Review  
Commissioner for Patents  
Crystal Park 5  
2451 Crystal Drive  
3<sup>rd</sup> Floor, Room 3D11  
Arlington, VA 22202

**EXPEDITED PETITION FOR FOREIGN FILING LICENSE  
PURSUANT TO 37 CFR SEC. 5.12 AND 5.13**

Sir:

A license for foreign filing under 35 U.S.C. Sec. 184 is hereby requested pursuant to the provisions of 37 CFR Sec. 5.12 and 5.13. The license for foreign filing is requested with respect to the attached legible copy of the patent application entitled "VERTICAL JFET LIMITED SILICON CARBIDE POWER METAL-OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS AND METHODS OF FABRICATING VERTICAL JFET LIMITED SILICON CARBIDE METAL-OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS," including 28 pages of specification, 14 sheets of drawings, and 60 claims, which is contemplated for foreign filing.

The inventor of the patent application is Sei-Hyung Ryu, residing at 123 Louben Valley Court, Cary, North Carolina 27513. The inventor is presently under obligation to assign his rights in the application to **Cree, Inc.**, a North Carolina corporation having a principal place of business at 4600 Silicon Drive, Durham, North Carolina 27703.

The attached patent application claims priority from and the benefit of United States Application Serial No. 60/435,212 filed December 20, 2002, entitled *Vertical*

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*JFET Limited Silicon Carbide Power Metal-Oxide Semiconductor Field Effect Transistors and Methods of Fabricating Vertical JFET Limited Silicon Carbide Metal-Oxide Semiconductor Field Effect Transistors.* Copies of the previously filed application, along with copies of the filing receipt and foreign filing license granted therein, are also attached.

It is respectfully requested that a copy of the foreign filing license be transmitted as soon as possible via (within 72 hours of the filing of this Petition) facsimile to:

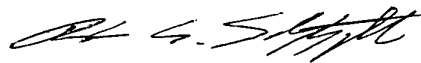
Rohan G. Sabapathypillai  
(919) 854-1401

The original foreign filing license should be mailed to:

Rohan G. Sabapathypillai  
Myers Bigel Sibley and Sajovec  
P.O. Box 37428  
Raleigh, North Carolina 27627.

Pursuant to 37 CFR Sec. 1.17(h), please charge my Deposit Account No. 50-0220 in the amount of \$130.00. The Commissioner is hereby authorized to charge any additional fees related to the filing of this petition to Deposit Account No. 50-0220. The Licensing and Review Division is respectfully requested to contact David D. Beatty at (919) 854-1400 if any issues should need to be addressed.

Respectfully submitted,



Rohan G. Sabapathypillai  
Registration No. 51,074

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Raleigh NC 27627  
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